

# FH8707

## N- Channel Enhancement Mode Power MOSFET

### Description

The FH8707 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications. It is ESD protected.

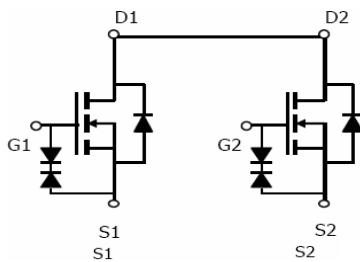
### General Features

- $V_{DS} = 16V, I_D = 13A$
- $R_{DS(ON)} < 7 \text{ m}\Omega @ V_{GS}=4.5V$
- $R_{DS(ON)} < 8 \text{ m}\Omega @ V_{GS}=3.8V$
- $R_{DS(ON)} < 9 \text{ m}\Omega @ V_{GS}=2.5V$
- ESD Rating: 2000V HBM

### Application

- PWM application
- Load switch

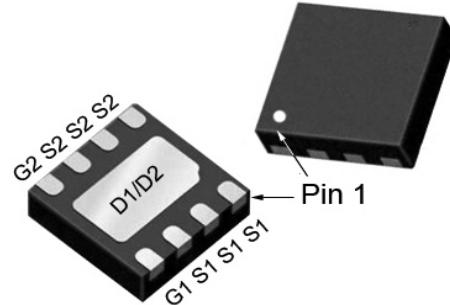
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package



Schematic diagram



Marking and pin assignment



DFN3x3-8L Pin assignment and Top / Bottom View

### Absolute Maximum Ratings ( $TA=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	16	V
Gate-Source Voltage	$V_{GS}$	$\pm 10$	V
Drain Current-Continuous	$I_D$	13	A
Drain Current-Pulsed (Note 1)	$I_{DM}$	53	A
Maximum Power Dissipation ( $TA=25^\circ\text{C}$ )	$P_D$	3	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	$^\circ\text{C}$

### Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	41.7	$^\circ\text{C/W}$
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### Electrical Characteristics ( $TA=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu\text{A}$	16		-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=13V, V_{GS}=0V$	-	-	1	$\mu\text{A}$

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 10V, V_{DS}=0V$	-	-	$\pm 10$	$\mu A$
<b>On Characteristics (Note 3)</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.45	0.8	1.2	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=6.0A$		4.5	7	$m\Omega$
		$V_{GS}=3.8V, I_D=5.0A$		5.5	8	$m\Omega$
		$V_{GS}=2.5V, I_D=4.0A$		7	9	$m\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}=5V, I_D=5A$	-	20	-	S
<b>Dynamic Characteristics (Note4)</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V, F=1.0MHz$	-	1310	-	PF
Output Capacitance	$C_{oss}$		-	264	-	PF
Reverse Transfer Capacitance	$C_{rss}$		-	235	-	PF
<b>Switching Characteristics (Note 4)</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=10V, R_L=1.35\Omega$ $V_{GS}=5V, R_{GEN}=3\Omega$	-	6		nS
Turn-on Rise Time	$t_r$		-	13		nS
Turn-Off Delay Time	$t_{d(off)}$		-	52		nS
Turn-Off Fall Time	$t_f$		-	16		nS
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=7A,$ $V_{GS}=4.5V$	-	15		nC
Gate-Source Charge	$Q_{gs}$		-	3	-	nC
Gate-Drain Charge	$Q_{gd}$		-	7	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}=0V, I_S=1A$	-	-	1.2	V
Diode Forward Current (Note 2)	$I_S$		-	-	7	A

**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

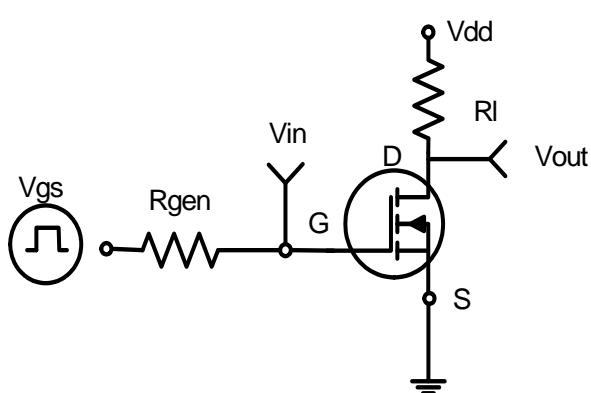


Figure 1:Switching Test Circuit

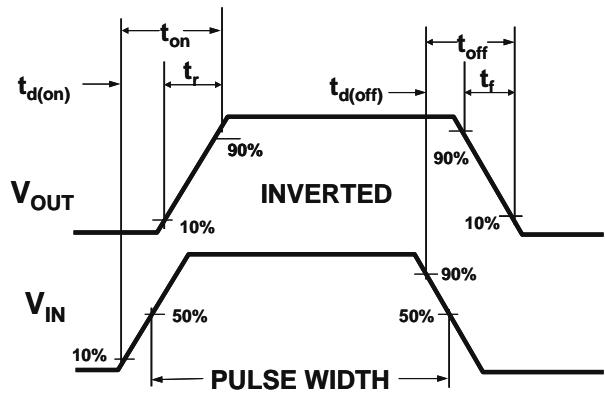


Figure 2:Switching Waveforms

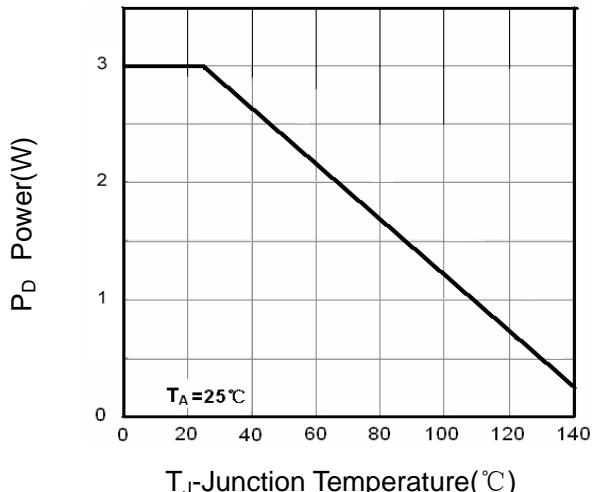


Figure 3 Power Dissipation

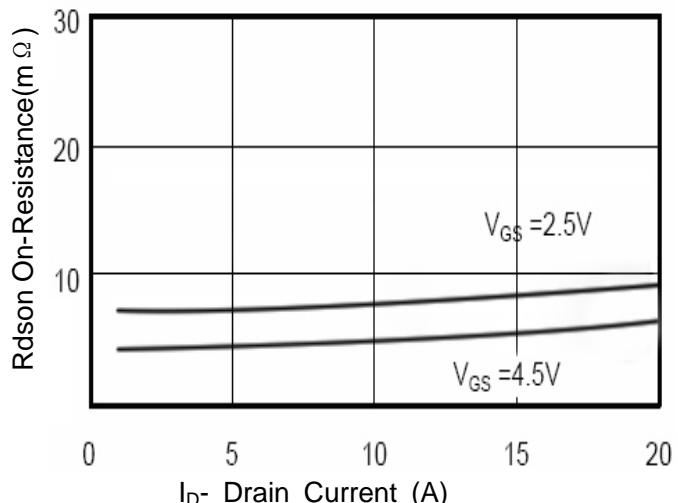


Figure 4 Drain-Source On-Resistance

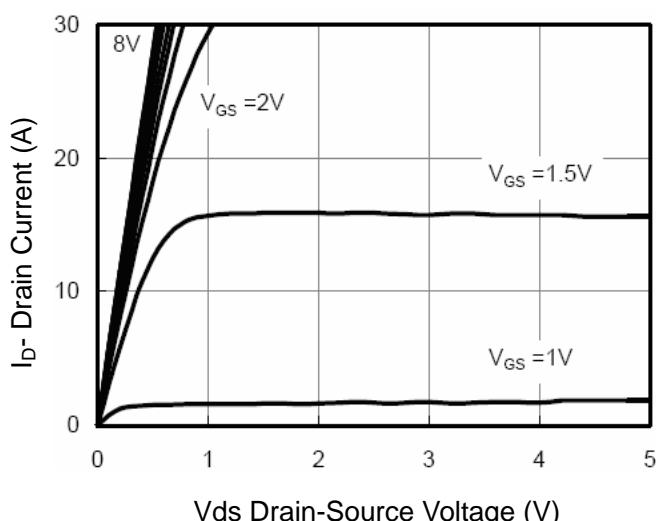


Figure 5 Output CHARACTERISTICS

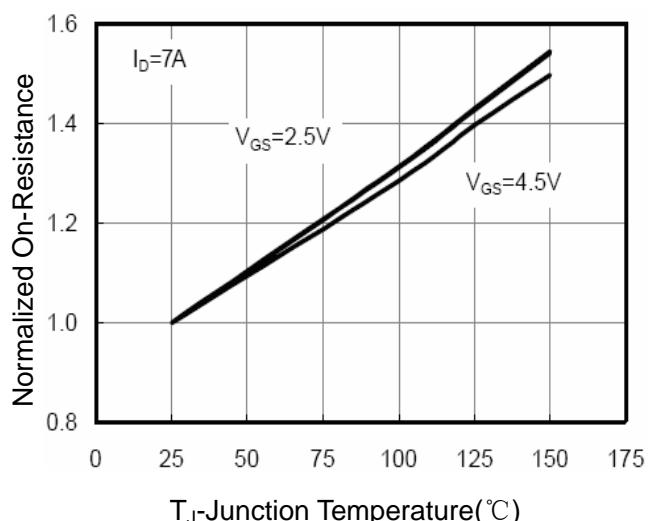
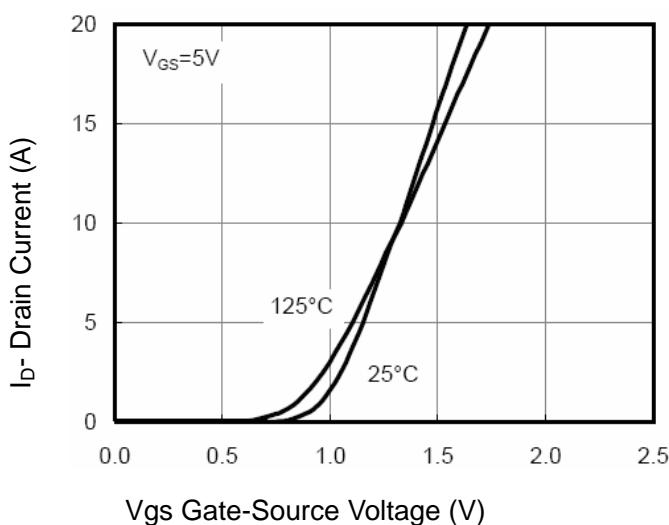
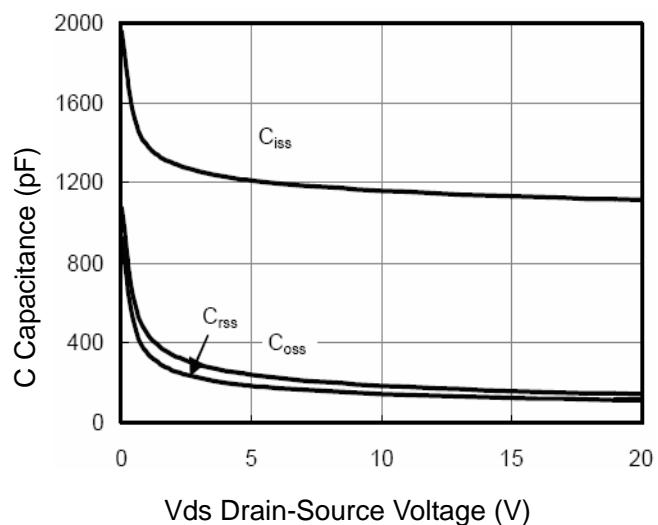


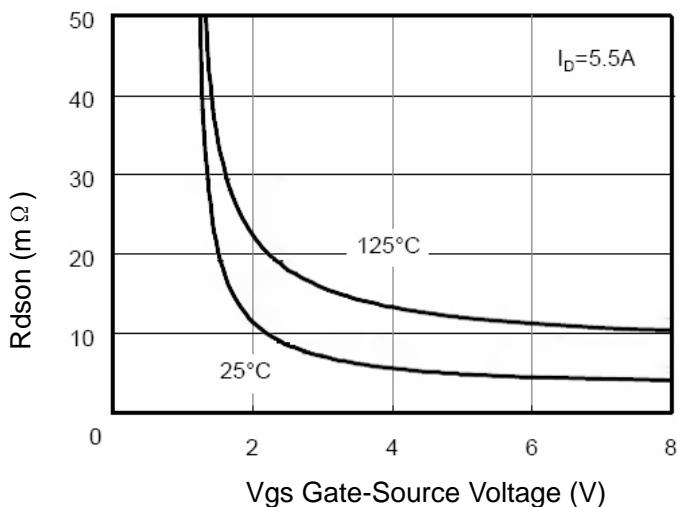
Figure 6 Drain-Source On-Resistance



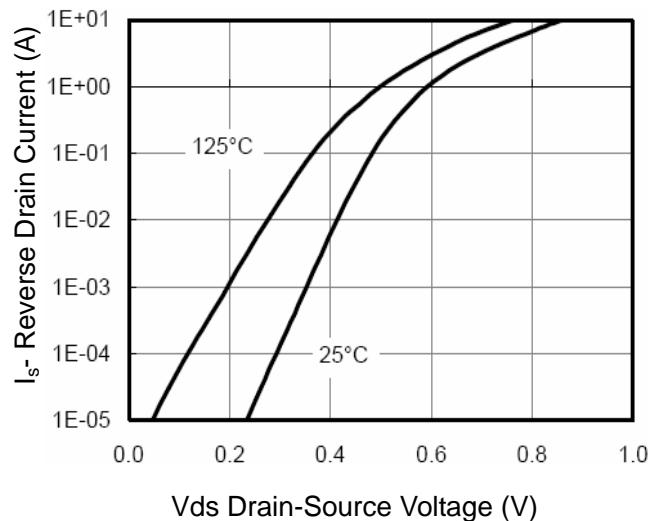
**Figure 7 Transfer Characteristics**



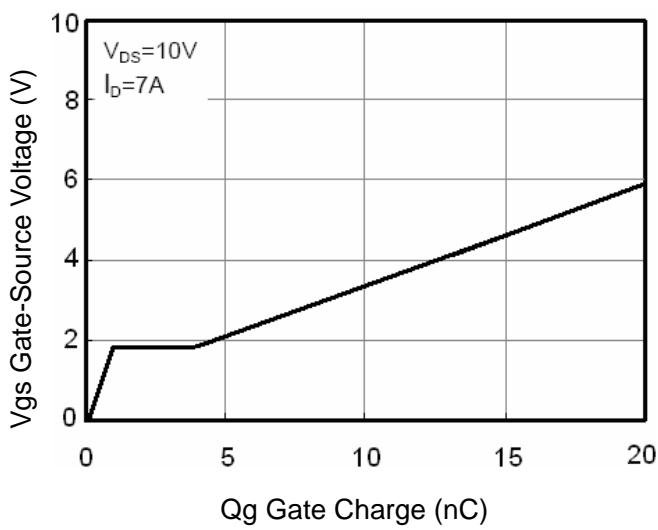
**Figure 8 Capacitance vs  $V_{DS}$**



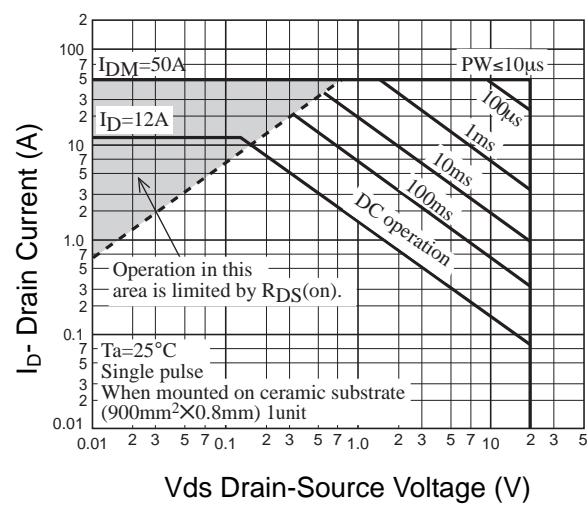
**Figure 9  $R_{DSON}$  vs  $V_{GS}$**



**Figure 10 Capacitance vs  $V_{DS}$**



**Figure 11 Gate Charge**



**Figure 12 Safe Operation Area**

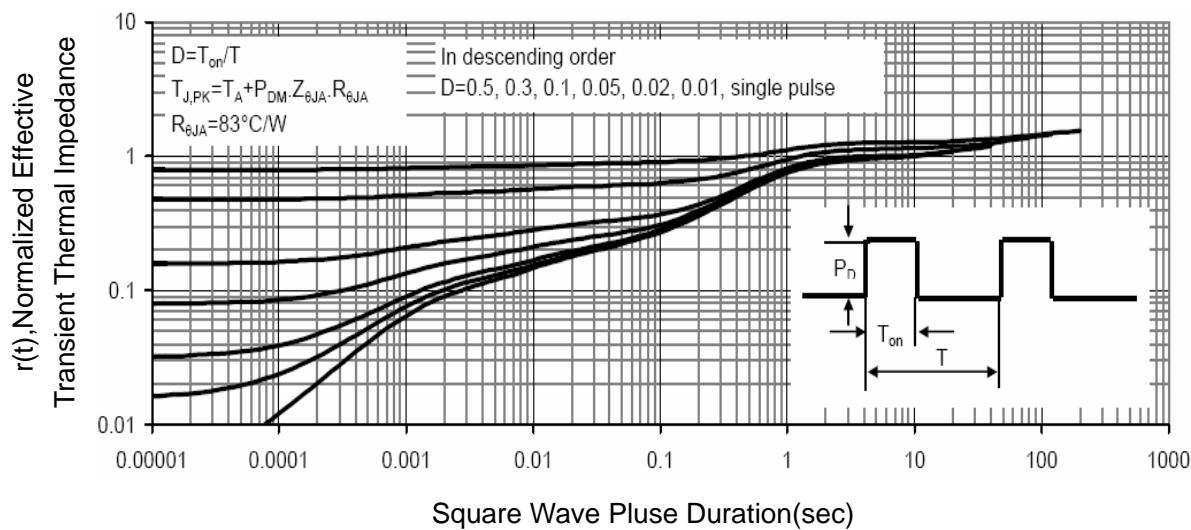
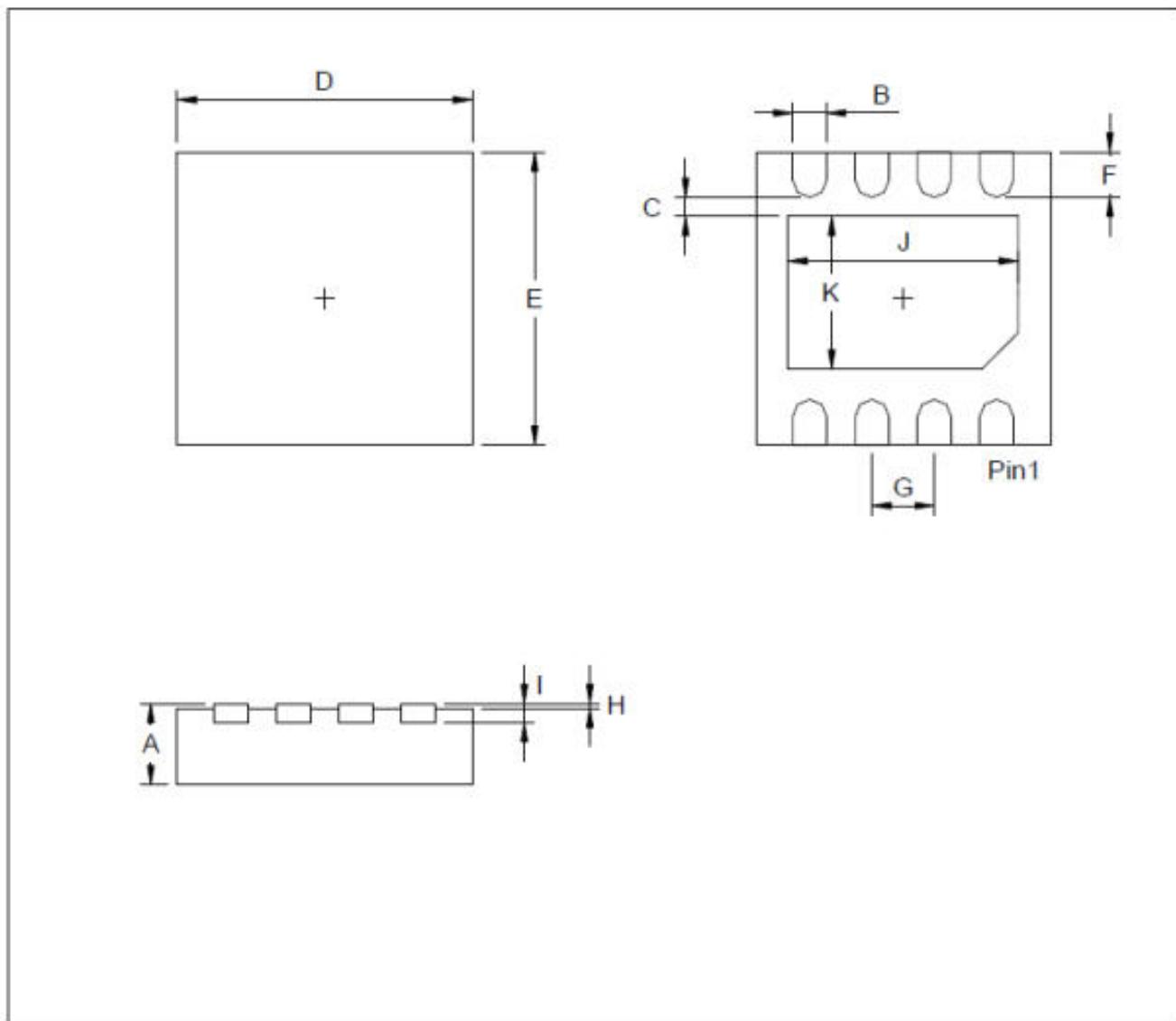


Figure 13 Normalized Maximum Transient Thermal Impedance

## Package Outline Dimensions : DFN3\*3-8L



Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	0.7		0.8	I		0.203	
B	0.25		0.35	J	2.2		2.4
C	0.2			K	1.4		1.6
D	2.924		3.076				
E	2.924		3.076				
F	0.324		0.476				
G		0.65					
H	0		0.05				